74HC4316; 74HCT4316

Quad single-pole single-throw analog switch

Rev. 4 — 15 October 2018

Product data sheet

1. General description

The 74HC4316; 74HCT4316 is a quad single pole, single throw analog switch (SPST). Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nS). When nS is LOW, the analog switch is turned off. When \overline{E} is HIGH all four analog switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- Input levels \(\overline{E}\) and nS inputs:
 - For 74HC4316: CMOS level
 - For 74HCT4316: TTL level
- · Low ON resistance:
 - 160 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - 120 Ω (typical) at V_{CC} V_{EE} = 6.0 V
 - 80 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation:
 - To enable 5 V logic to communicate with ±5 V analog signals
- Typical break-before-make built in
- · Specified in compliance with JEDEC standard no. 7A
- · ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Signal gating
- Modulation
- Demodulation
- Chopper

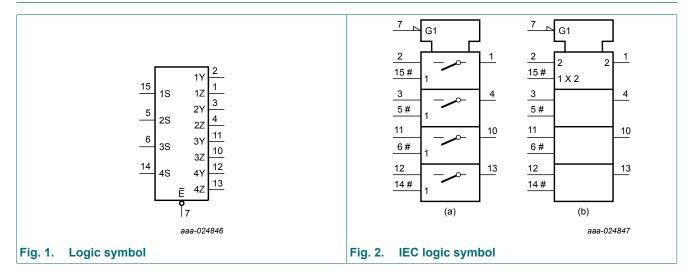


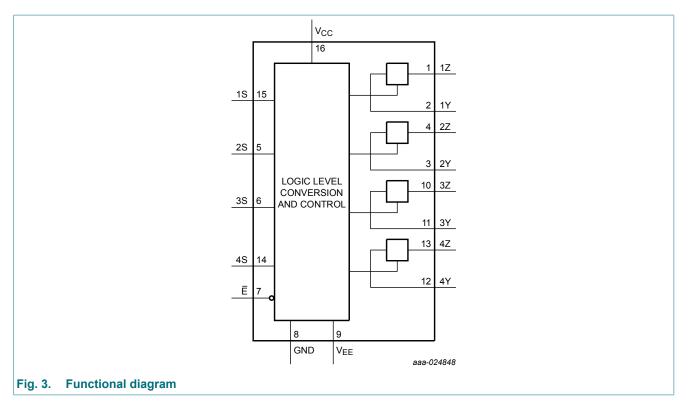
4. Ordering information

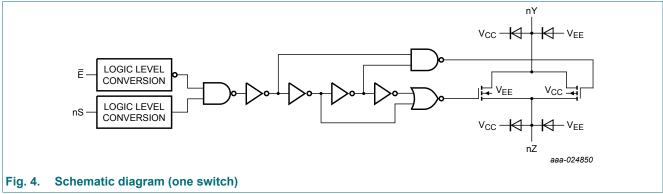
Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74HC4316D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74HCT4316D									
74HC4316DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1					
74HCT4316DB			body width 5.3 mm						
74HC4316PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1					
74HCT4316PW			body width 4.4 mm						

5. Functional diagram

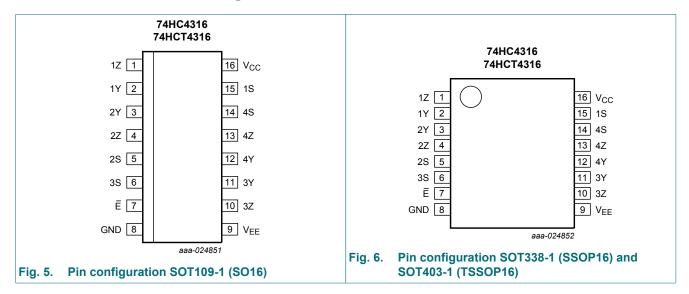






6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Tuble 2.1 III description								
Symbol	Pin	Description						
1Z, 2Z, 3Z, 4Z	1, 4, 10, 13	independent input or output						
1Y, 2Y, 3Y, 4Y	2, 3, 11, 12	independent input or output						
Ē	7	enable input (active LOW)						
GND	8	ground (0 V)						
V _{EE}	9	negative supply voltage						
1S, 2S, 3S, 4S	15, 5, 6, 14	select input (active HIGH)						
V _{CC}	14	positive supply voltage						

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input		Switch
Ē	nS	
L	L	OFF
L	Н	ON
Н	X	OFF

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	$V_{SW} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$ [1]	-	±25	mA
I _{EE}	supply current		-	20	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	500	mW
Р	power dissipation	per switch	-	100	mW

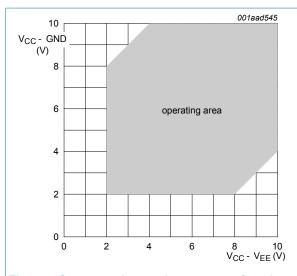
^[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows in terminals nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nY. In this case there is no limit for the voltage drop across the switch, but the voltages at nY and nZ may not exceed V_{CC} or V_{EE} .

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	7	4HC431	6	74HCT4316			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see Fig. 7 and Fig. 8							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{EE} - GND	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V _{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	and fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	35	-	-	-	ns/V

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
For (T)SSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.





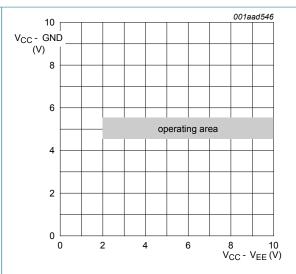


Fig. 8. Guaranteed operating area as a function of the supply voltages for 74HCT4316

10. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4316 and 74HCT4316

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Fig. 9.

V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

Vos is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

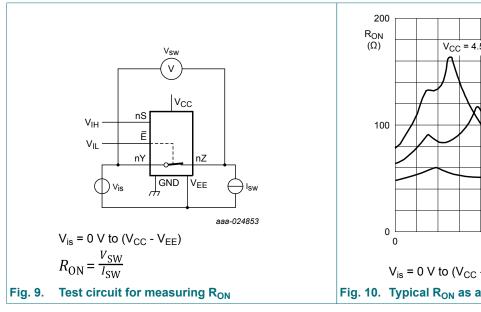
For 74HC4316: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4316: V_{CC} - GND = 4.5 V and 5.5 V; V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions	25	°C	-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Тур	Max	Min	Max	Min	Max	
R _{ON(peak)} ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE} [1]								
	V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μ A	-	-	-	-	-	-	Ω	
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μ A	160	320	-	400	-	480	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μ A	120	240	-	300	-	360	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μ A	85	170	-	215	-	255	Ω

Symbol	Parameter	Conditions	25	°C	-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Тур	Max	Min	Max	Min	Max	
R _{ON(rail)}	ON resistance	$V_{is} = V_{EE}$ [1]							
	(rail)	$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V};$ $I_{SW} = 100 \mu\text{A}$	160	-	-	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA	80	160	-	200	-	240	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA	70	140	-	175	-	210	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	60	120	-	150	-	180	Ω
		$V_{is} = V_{CC} $ [1]							
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	170	-	-	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μ A	90	180	-	225	-	270	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$	80	160	-	200	-	240	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA	65	135	-	170	-	205	Ω
ΔR_{ON}	ON resistance	$V_{is} = V_{CC}$ to V_{EE} [1]							
	mismatch between	$V_{CC} = 2.0 \text{ V}; V_{EE} = 0 \text{ V}$	-	-	-	-	-	-	Ω
	channels	$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	16	-	-	-	-	-	Ω
		$V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	9	-	-	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V	6	-	-	-	-	-	Ω

[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.



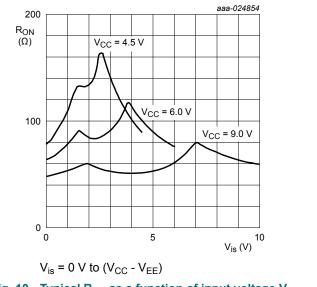


Table 7. Static characteristics 74HC4316

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.3	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
l _l	input leakage current	$V_I = V_{CC}$ or GND				
		C = 2.0 V	μΑ			
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	±0.2	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 11</u>	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	±0.1	μΑ	
lcc	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	8.0	μΑ
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	16.0	V V V V V V V V V V V V V V V V V V V
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	5	-	pF
T _{amb} = -4	10 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		3.15 2.4 3.16 2.9.0 V 3.2 3.2 3.2 3.2 3.3 4.3 3.3 5.2 3.4 6.3 3.1 5.2 3.2 6.3 3.3 7.3 3.3 7.	-	V		
V_{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage current	$V_I = V_{CC}$ or GND				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	±2.0	μΑ
S(OFF)	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 11</u>	-	-	±1.0	μΑ
S(ON)	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μΑ
Icc	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	80.0	μΑ
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	160.0	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C		'			
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	1.5 3.15 4.2 6.3	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage current	V _I = V _{CC} or GND				
l _l i		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	- V - V 0.5 V 1.35 V 1.8 V 2.7 V ±1.0 μA ±2.0 μA	μΑ
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see Fig. 11	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	160	μΑ
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	320	μΑ

Table 8. Static characteristics 74HCT4316

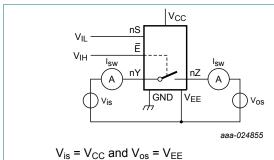
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

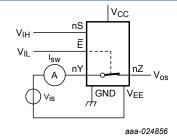
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±0.1	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$	-	-	±0.1	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	μΑ
Δl _{CC}	additional supply current	nS and \overline{E} ; per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	50	180	μA
C _I	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance		-	5	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +85 °C				'	1
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see Fig. 11}$	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160	μΑ
ΔI _{CC}	additional supply current	nS and \overline{E} ; per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	225	μΑ
T _{amb} = -2	40 °C to +125 °C		<u> </u>		'	"
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$	-	-	±1.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320	μΑ
ΔI _{CC}	additional supply current	nS and \overline{E} ; per input pin; $V_1 = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $V_{EE} = 0 \text{ V}$	-	-	245	μΑ



 $V_{is} = V_{CC}$ and $V_{os} = V_{EE}$ $V_{is} = V_{EE}$ and $V_{os} = V_{CC}$

Fig. 11. Test circuit for measuring OFF-state leakage current



 $V_{is} = V_{CC}$ and $V_{os} = open$

 $V_{is} = V_{EE}$ and $V_{os} = open$

Fig. 12. Test circuit for measuring ON-state leakage current

11. Dynamic characteristics

Table 9. Dynamic characteristics

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF unless specified otherwise; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25	°C	-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Тур	Max	Min	Max	Min	Max	
74HC43	16								
t _{pd}	propagation delay	nY to nZ or nZ to nY; $R_L = \infty \Omega$; [1] see Fig. 13							
		V _{CC} = 2.0 V; V _{EE} = 0 V	17	60	-	75	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	6	12	-	15	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	5	10	-	13	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	4	8	-	10	-	12	ns
t _{off}	turn-off time	E to nY or nZ; see Fig. 14 [2]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	63	220	-	275	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	23	44	-	55	-	66	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V;C _L = 15 pF	C _L = 15 pF 20	ns					
		V _{CC} = 6.0 V; V _{EE} = 0 V	18	37	-	47	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	39	-	49	-	59	ns
		nS to nY or nZ; see Fig. 14 [2]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	20	35	-	44	-	53	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	16	-	-	-	-	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	16	30	-	37	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	18	36	-	45	-	90 18 15 12 330 66 - 56 59 265 53 -	ns
t _{on}	turn-on time	Ē to nY or nZ; see Fig. 14 [3]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	61	205	-	255	-	310	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	22	41	-	51	-	62	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19	-	-	-	-	18 15 12 330 66 - 56 59 265 53 - 45 54 310 62 - 53 56 265 53 - 45 51	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	18	35	-	43	-	53	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	19	37	-	47	-	56	ns
		nS to nY or nZ; see Fig. 14 [3]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	52	175	-	220	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	19	35	-	44	-	53	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	16	-	-	-	-	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	15	30	-	37	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	17	34	-	43	-	51	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [4]	13	-	-	-	-	-	pF

Symbol	Parameter	Conditions	25	°C	-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Тур	Max	Min	Max	Min	Max	
74HCT4	316				,				
t _{pd} propagati delay		nY to nZ or nZ to nY; $R_L = \infty \Omega$; [1] see Fig. 13							
		V _{CC} = 4.5 V; V _{EE} = 0 V	6	12	-	15	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	4	8	-	10	-	12	ns
t _{PZH}	OFF-state	E to nY or nZ; see Fig. 14							
	to HIGH propagation	V _{CC} = 4.5 V; V _{EE} = 0 V	22	44	-	55	-	66	ns
	delay	V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	42	-	53	-	63	ns
		nS to nY or nZ; see Fig. 14							
		V _{CC} = 4.5 V; V _{EE} = 0 V	20	40	-	53	-	60	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	17	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	17	34	-	43	-	51	ns
t _{PZL}	OFF-state to LOW propagation delay	E to nY or nZ; see Fig. 14							
		V _{CC} = 4.5 V; V _{EE} = 0 V	28	56	-	70	-	84	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	24	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	42	-	53	-	63	ns
		nS to nY or nZ; see Fig. 14							
		V _{CC} = 4.5 V; V _{EE} = 0 V	25	50	-	63	-	75	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	21	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	17	34	-	43	-	51	ns
t _{off}	turn-off time	E to nY or nZ; see Fig. 14 [2]							
		V _{CC} = 4.5 V; V _{EE} = 0 V	25	50	-	63	-	75	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	21	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	23	46	-	58	-	69	ns
		nS to nY or nZ; see Fig. 14 [2]							
		V _{CC} = 4.5 V; V _{EE} = 0 V	22	44	-	55	-	66	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	20	40	-	50	-	60	ns
C_{PD}	power dissipation capacitance	per switch; $V_I = GND$ to $(V_{CC} - 1.5 V)$ [4]	14	-	-	-	-	-	pF

 $[\]begin{array}{ll} \hbox{[1]} & t_{pd} \hbox{ is the same as } t_{PHL} \hbox{ and } t_{PLH}. \\ \hbox{[2]} & t_{off} \hbox{ is the same as } t_{PHZ} \hbox{ and } t_{PLZ}. \end{array}$

 $P_D = C_{PD} x V_{CC}^2 x f_i + \sum ((C_L + C_{sw}) x V_{CC}^2 x f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 $\sum ((C_L + C_{sw}) \times V_{CC}^2 \times f_0) = \text{sum of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

 t_{on} is the same as t_{PZH} and t_{PZL} . t_{PD} is used to determine the dynamic power dissipation (t_{PD} in t_{PD}).

11.1. Waveforms and test circuit

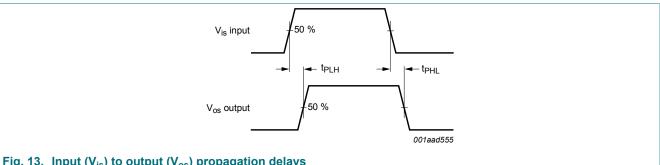


Fig. 13. Input (V_{is}) to output (V_{os}) propagation delays

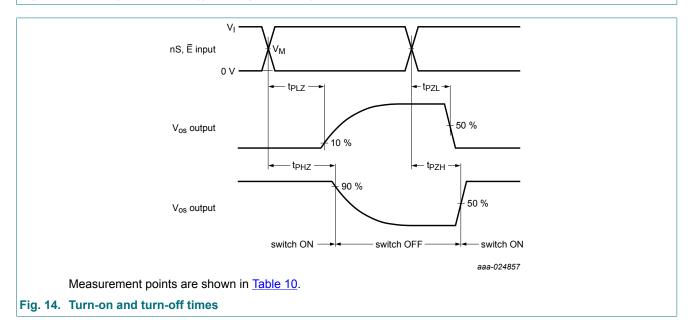
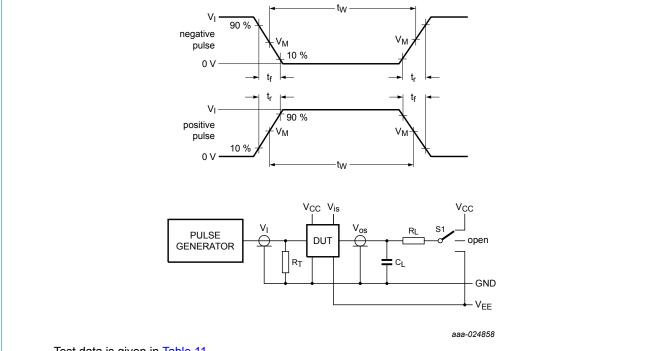


Table 10. Measurement points

Туре	V _I	V _M
74HC4316	V _{CC}	0.5V _{CC}
74HCT4316	3.0 V	1.3 V



Test data is given in Table 11.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 \mathbf{C}_{L} = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig. 15. Test circuit for measuring switching times

Table 11. Test data

Test	Input				Output	S1 position		
	E	nS	Switch nY (nZ)	t _r , t _f		Switch nZ (nY)		
	Vı		V _{is}	at f _{max}	other [1]	CL	R _L	
t _{PHL} , t _{PLH}	[2]		GND to V _{CC}	< 2 ns	6 ns	50 pF	-	open
t_{PHZ},t_{PZH}	[2]		V _{CC}	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	V _{EE}
t_{PLZ},t_{PZL}	[2]		V _{EE}	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}

 t_r = t_f = 6 ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

[2] V_I values:

> For 74HC4316: V_I = V_{CC} For 74HCT4316: V_I = 3 V

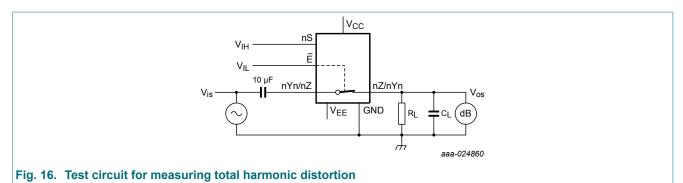
11.2. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

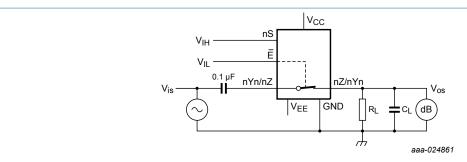
Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C; C_L = 50 pF. V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input. V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic	f_i = 1 kHz; R_L = 10 k Ω ; see <u>Fig. 16</u>				
	distortion	V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.80	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V	-	0.40	-	%
		f_i = 10 kHz; R_L = 10 k Ω ; see <u>Fig. 16</u>				
		V_{is} = 4.0 V (p-p); V_{CC} = 2.25 V; V_{EE} = -2.25 V	-	2.40	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V	-	1.20	-	%
f _(-3dB)	-3 dB frequency	$R_L = 50 \Omega$; $C_L = 10 pF$; see <u>Fig. 17</u> [1]				
	response	V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	150	-	MHz
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	160	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $f_i = 1 MHz$; see Fig. 18 [2]				
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	-50	-	dB
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-50	-	dB
V _{ct}	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600 \ \Omega$; $f_i = 1 \ MHz$; \overline{E} or nS square wave between V_{CC} and GND; $t_r = t_f = 6 \ ns$; see Fig. 19				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	220	-	mV
Xtalk	crosstalk	between switches; $R_L = 600 \Omega$; $f_i = 1 MHz$; see Fig. 20 [2]				
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	-60	-	dB
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-60	-	dB

- [1] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).
- [2] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

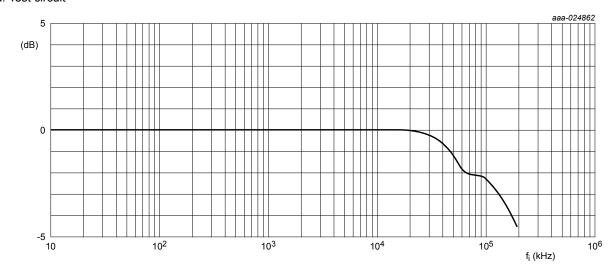


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 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 50 Ω ; R_S = 1 k Ω .

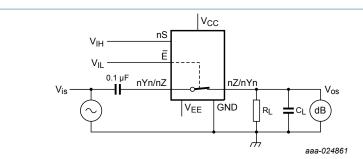
a. Test circuit



b. Typical -3 dB frequency response

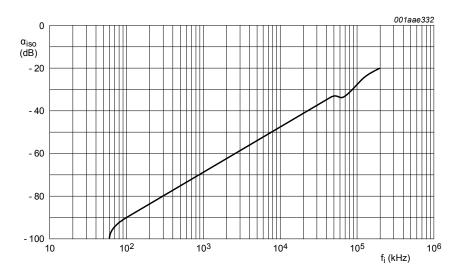
Fig. 17. -3 dB frequency response

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 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 600 Ω ; R_S = 1 k Ω .

a. Test circuit



b. Isolation (OFF-state) as a function of frequency

Fig. 18. Isolation (OFF-state) as a function of frequency

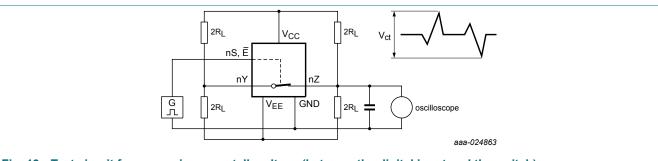
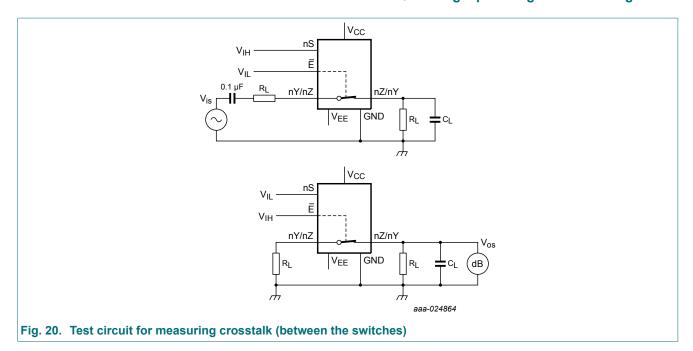
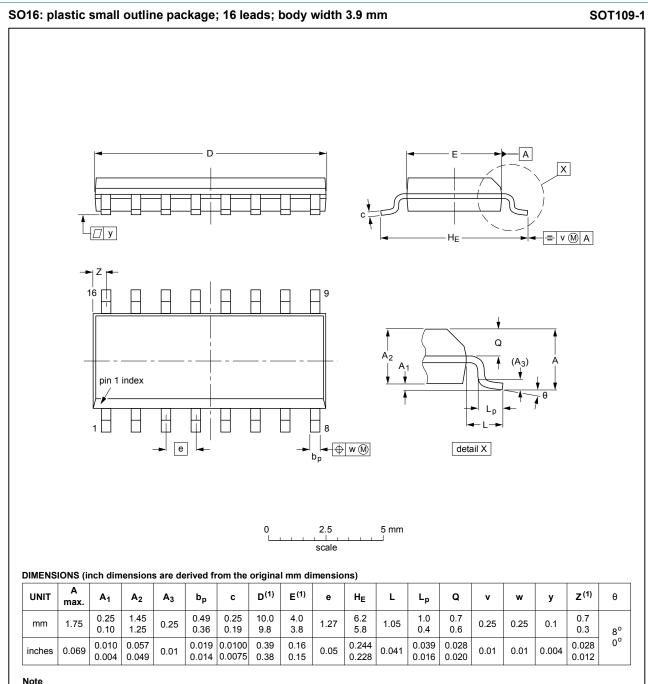


Fig. 19. Test circuit for measuring crosstalk voltage (between the digital input and the switch)



12. Package outline



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig. 21. Package outline SOT109-1 (SO16)

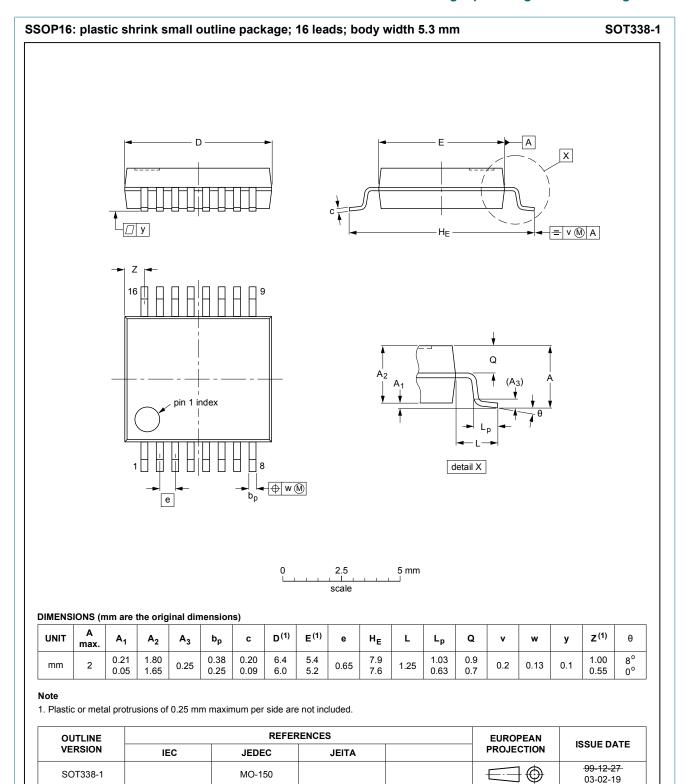
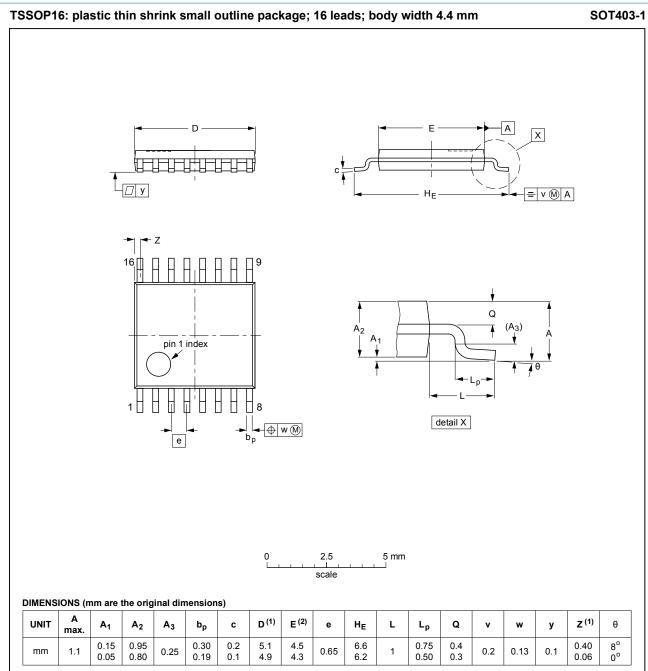


Fig. 22. Package outline SOT338-1 (SSOP16)



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES		EUROPEAN PROJECTION	ISSUE DATE
VERSION	IEC	JEDEC	JEITA			ISSUE DATE
SOT403-1		MO-153				99-12-27 03-02-18

Fig. 23. Package outline SOT403-1 (TSSOP16)

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT4316 v.4	20181016	Product data sheet	-	74HC_HCT4316 v.3	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guinnernament. Legal texts have been adapted to the new company name where appropriate. 				
74HC_HCT4316 v.3	20170102	Product data sheet	-	74HC_HCT4316_CNV v.2	
Modifications:	guidelines of N • Legal texts hav	his data sheet has been redes IXP Semiconductors. ye been adapted to the new conductors. 74HC4316N and 74HCT4316	ompany name where	·	
74HC_HCT4316_CNV v.2	19930901	Product specification	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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